

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	272	(generator) same (bias\$3 with (electrostatic ESD))	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 10:53
L2	21	(generator) same (bias\$3 with (electrostatic ESD) with pulse)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 10:54
L3	30	(generator) same (bias\$3 with (electrostatic ESD) with pulse\$1)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 11:10
L4	62	(bias\$3 near3 source) with ((electrostatic near3 pulse\$1) or ESD)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 11:12
L5	44	(bias\$3 adj3 source) with ((electrostatic near3 pulse\$1) or ESD)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 11:26
L6	3	("5646808" "5452171" "5740000").pn.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 11:33
L7	1	"20050030043"	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 15:02
L8	82	(Electrostatic ESD) with (lvtscr)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 12:49
L9	16	(Electrostatic ESD) with (lvtscr) with gate	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 13:21
L10	8	(Electrostatic ESD) with (fod) with base	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 13:29
L11	1	"6153499".pn.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 13:30
L12	1	"5828103".pn.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 13:43

L13	1	"5519327".pn.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 13:44
L14	46	257/48.ccls. and electrostatic	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 13:44
L15	52	257/48.ccls. and (electrostatic ESD)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 13:44
L16	1	"5519327".pn.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 14:59
L17	14	((zero no) near3 (leakage adj current)) with (operational blown broke)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 15:01
L18	0	((zero no) near3 (leakage adj current)) with (transistor) with (blown broke broken)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 15:01
L19	1	"20050030043" and ((leakage adj current) with before)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 15:02
L20	1	"20050030043" and ((leakage adj current) same before)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 15:05
L21	1	"20050030043" and (no with (leakage adj current))	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 15:18
L22	2	("4823088" "5675260").pn.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 15:18
S1	2408	((electrostatic near3 discharge) (ESD)) with (semiconductor\$1)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/04 10:52
S2	9	S1 and 324/452,456.ccls.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/02 09:17

S3	13	S1 and 324/765.ccls.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/02 09:02
S4	1426	S1 and (test\$3 measur\$3 determin\$3)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/02 09:04
S5	336	((electrostatic near3 discharge) (ESD)) with (semiconductor\$1)) same (test\$3 measur\$3 determin\$3)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/02 09:05
S6	9	("4823088").URPN.	USPAT	OR	OFF	2005/05/02 10:15
S7	8	("5675260").URPN.	USPAT	OR	OFF	2005/05/02 11:53
S8	1	"20050030043"	US-PGPUB; USPAT	OR	OFF	2005/05/02 11:54
S9	11	("4775640" "5132612" "5201415" "5383097" "5491427" "5519327" "5523699" "5644249" "5675260" "5804977" "6054863").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/02 13:32
S10	42	((electrostatic ESD) with (transistor)) and (transmission adj2 line adj2 puls\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/02 13:34
S11	34	324/763-769.ccls. and ((electrostatic ESD) near4 (semiconductor\$1 transistor\$1))	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/02 14:09
S12	11	("4775640" "5132612" "5201415" "5383097" "5491427" "5519327" "5523699" "5644249" "5675260" "5804977" "6054863").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/02 14:18
S13	7	("5132612").URPN.	USPAT	OR	OFF	2005/05/02 14:46
S14	11	("4775640" "5132612" "5201415" "5383097" "5491427" "5519327" "5523699" "5644249" "5675260" "5804977" "6054863").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/02 15:17
S15	1	(324/713,719 or 257/48.ccls. or 702/118-121.ccls.) and (transmission adj2 line adj2 puls\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/02 15:18
S16	6	324/452-458.ccls. and (transmission adj2 line adj2 puls\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/02 15:26

S17	194	324/763-769.ccls. and (electrostatic)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/02 16:31
S18	14	(transmission adj2 line adj2 puls\$4).ti.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/02 16:31
S19	58	(transmission adj2 line adj2 puls\$4).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/02 16:51
S20	3	(transmission adj2 line adj2 puls\$4) and (electrostatic near5 pulse\$1)	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/02 17:04
S21	22	(transmission adj2 line adj2 puls\$4) and (electrostatic near5 pulse\$1)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/02 17:05
S22	23	(transmission adj2 line adj2 puls\$4) and (electrostatic near5 (pulse\$1 signal\$1))	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/02 17:05
S23	1	"6250601".pn.	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/03 11:25
S24	7	(measure with electrostatic) with ((multiple plurality three many) near2 (position\$1 place\$1 point\$1))	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/03 16:05
S25	9	(electrostatic near4 (pulse\$1 signal\$1)) with ((multiple plurality three many) near2 (position\$1 place\$1 point\$1))	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/03 16:10
S26	61	324/452,456.ccls. and (transistor\$1 semiconductor\$1 wafer)	US-PGPUB; USPAT; USOCR; EPO	OR	OFF	2005/05/03 16:11